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2823

PATENT
Customer No. 22,852
Attorney Docket No. 04329.2306

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
)
Yoshio Ozawa, et al.) Group Art Unit: 2823
)
Application No.: 09/559,757) Examiner: Pham, Thanh V.
)
Filed: April 27, 2000)
)
For: METHOD OF MANUFACTURING)
A SEMICONDUCTOR DEVICE)
USING AN OXIDATION)
PROCESS (As Amended Hereby))

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

RECEIVED
SEP 22 2003
TECHNOLOGY CENTER 2800

AMENDMENT

In reply to the Office Action of June 24, 2003, with a period for response extending through September 24, 2003, please amend the application as follows. Applicants also respectfully request the Examiner's reconsideration in view of the remarks that follow:

Amendment to the Title is shown on page 2.

Amendments to the Specification are shown on page 3.

Amendments to the Drawings are made in the attached replacement sheets and are discussed in the **Remarks** section of this paper.

Remarks begin on page 4.

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AMENDMENT TO THE TITLE:

Please amend the title of the application as follows. On page 1, please replace the title at line 2 with the following title:

~~SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THEREOF~~ A
SEMICONDUCTOR DEVICE USING AN OXIDATION PROCESS

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